

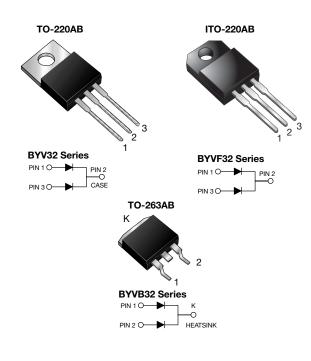
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Vishay General Semiconductor

Dual Common-Cathode Ultrafast Rectifier



PRIMARY CHARACTERISTICS					
I _{F(AV)}	18 A				
V _{RRM}	50 V to 200 V				
I _{FSM}	150 A				
t _{rr}	25 ns				
V _F	0.85 V				
T _J max.	150 °C				
Package	TO-220AB, ITO-220AB, TO-263AB				
Diode variations	Common cathode				

FEATURES

- Power pack
- · Glass passivated chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commerical grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

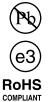
MAXIMUM RATINGS ($T_c = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	V		
Maximum RMS voltage	V _{RMS}	35	70	105	140	V		
Maximum DC blocking voltage	V _{DC}	50	100	150	200	V		
Maximum average forward rectified current at T_C = 125 °C	I _{F(AV)}	18				А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150				А		
Operating storage and temperature range	T _J , T _{STG}	- 65 to + 150 °				°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500 V			V			

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ELECTRICAL CHARACTERISTICS ($T_c = 25 \ ^{\circ}C$ unless otherwise noted)								
PARAMETER	TEST CO	NDITIONS	SYMBOL	OL BYV32-50 BYV32-100 BYV32-150 BYV32-2		BYV32-200	UNIT	
Maximum instantaneous	I _F = 20 A	$T_J = 25 \ ^\circ C$	V _F ⁽¹⁾	1.15				v
forward voltage per diode	_F = 5.0 A	T _J = 100 °C	VF	0.85				
Maximum DC reverse		T _J = 25 °C		10				
current per diode at rated DC blocking voltage		T _J = 100 °C	I _R	600			μA	
Maximum reverse recovery time per diode	$ I_F = 1 \text{ A}, V_R = 30 \text{ V} \\ dI/dt = 100 \text{ A}/\mu\text{s}, I_{rr} = 10 \text{ \% } I_{RM} $		t _{rr}	25				ns
Typical junction capacitance per diode	4.0 V, 1 MHz	V, 1 MHz		45			pF	

Note

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		BYV	BYVF	BYVB	UNIT	
Typical thermal resistance from junction to case per diode	$R_{ ext{ heta}JC}$	1.6	5.0	1.6	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	BYV32-200-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	BYVF32-200-E3/45	1.97	45	50/tube	Tube		
TO-263AB	BYVB32-200-E3/45	1.35	45	50/tube	Tube		
TO-263AB	BYVB32-200-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	BYV32-200HE3/45 ⁽¹⁾	1.85	45	50/tube	Tube		
ITO-220AB	BYVF32-200HE3/45 (1)	1.97	45	50/tube	Tube		
TO-263AB	BYVB32-200HE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	BYVB32-200HE3/81 (1)	1.35	81	800/reel	Tape and reel		

Note

⁽¹⁾ AEC-Q101 qualified



BYV32-xxx, BYVF32-xxx, BYVB32-xxx

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

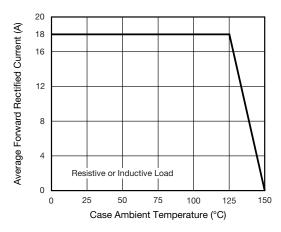


Fig. 1 - Forward Current Derating Curve

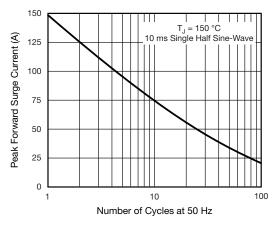


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

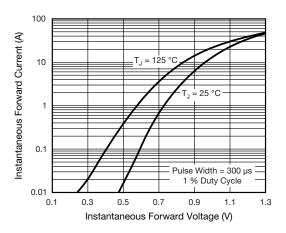


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

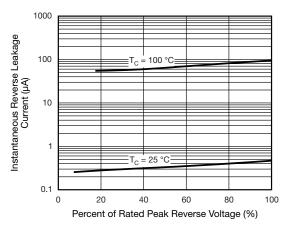


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

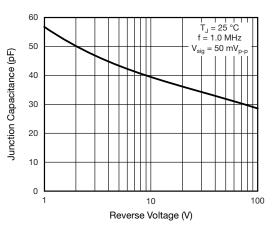


Fig. 5 - Typical Junction Capacitance Per Diode

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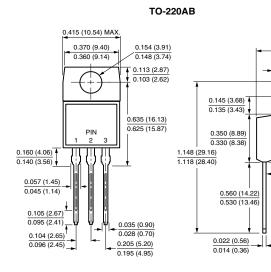
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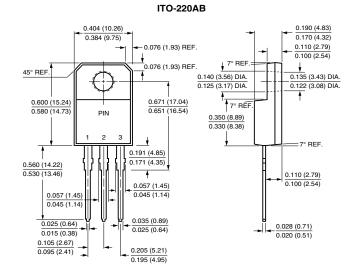


BYV32-xxx, BYVF32-xxx, BYVB32-xxx

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





TO-263AB

0.185 (4.70) 0.175 (4.44)

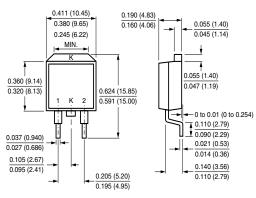
0.055 (1.39)

0.045 (1.14)

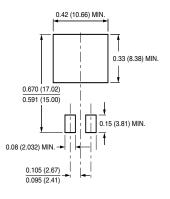
0.603 (15.32)

0.573 (14.55)

0.110 (2.79) 0.100 (2.54)



Mounting Pad Layout



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